

Differential Precision Rectifier using Single CMOS DVCC

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ABSTRACT

Three novel differential precision rectifier circuits are realized using single CMOS differential voltage current conveyor. One of the realized differential precision rectifiers provides half wave voltage output. The other two circuits give full wave voltage outputs. Among the two full wave differential precision rectifiers, one circuit provides single ended voltage output while other full wave differential precision rectifier gives differential full wave voltage output. All the realized differential precision rectifiers possess the gain control facility through two resistors ratio. The realized differential precision rectifier circuits are designed and verified using PSPICE and the results thus obtained justify the theory.

Keywords

Current conveyors, DVCC, precision rectifiers.

1. INTRODUCTION

For over last two decades the current conveyors have been dominating in the area of analog signal processing due to their functional versatility in addition to higher signal bandwidth and greater linearity. As a result vast variety of linear and nonlinear analog signal processing applications are reported in technical literature [1-32].

Among nonlinear analog signal processing applications the precision rectifiers form an important building block. In such rectifiers, the threshold voltages associated with diodes are overcome and hence enable the rectification at relatively low signal levels required for signal processing applications. With the advent of current conveyors, which offer a number of advantages over other devices, many precision rectifiers using current conveyors have been recently reported in literature [21-32]. However, many of them use a complex circuitry and provide only single ended input and output.

In this paper three new differential precision rectifier (DPR) circuits are presented using only single differential voltage current conveyor (DVCC) along with one or two CMOS pair. One of the realized differential precision rectifiers provides half wave voltage output. The other two circuits give full wave voltage outputs. Among the two full wave circuits, the first one provides differential precision rectifier with single ended output (DPRSO), while other full wave differential precision rectifier gives differential output (DPRDO). All the realized differential precision rectifiers possess the gain control facility through two resistors ratio. The realized differential precision rectifier circuits are designed and

verified using PSPICE and the results thus obtained justify the theory.

2. THE CMOS DVCC

The differential voltage current conveyor (DVCC) symbol is shown in “Figure 1(a)” and its CMOS implementation with two Z+ and one Z- outputs is shown in “Figure 1(b)”. The transfer matrix of the DVCC can be expressed as

$$\begin{bmatrix} I_{Y1} \\ I_{Y2} \\ V_X \\ I_{Z+} \\ I_{Z-} \end{bmatrix} = \begin{bmatrix} 0 & 0 & 0 & 0 & 0 \\ 0 & 0 & 0 & 0 & 0 \\ 1 & -1 & 0 & 0 & 0 \\ 0 & 0 & 1 & 0 & 0 \\ 0 & 0 & -1 & 0 & 0 \end{bmatrix} \begin{bmatrix} V_{Y1} \\ V_{Y2} \\ I_X \\ V_{Z+} \\ V_{Z-} \end{bmatrix} \quad (1)$$

Thus the port voltages and currents for the DVCC can be expressed as

$$\begin{aligned} I_{Y1} &= I_{Y2} = 0 \\ V_X &= V_{Y1} - V_{Y2} \\ I_{Z+} &= +I_X \\ I_{Z-} &= -I_X \end{aligned} \quad (2)$$

The additional number of Z+ or Z- outputs may be added as per requirement just by connecting in parallel a set of PMOS and NMOS for each output as shown in “Figure 1(b)”.

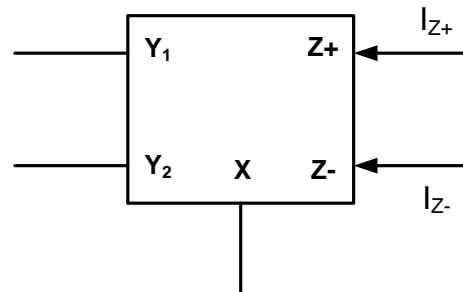


Fig 1(a): Symbol for DVCC

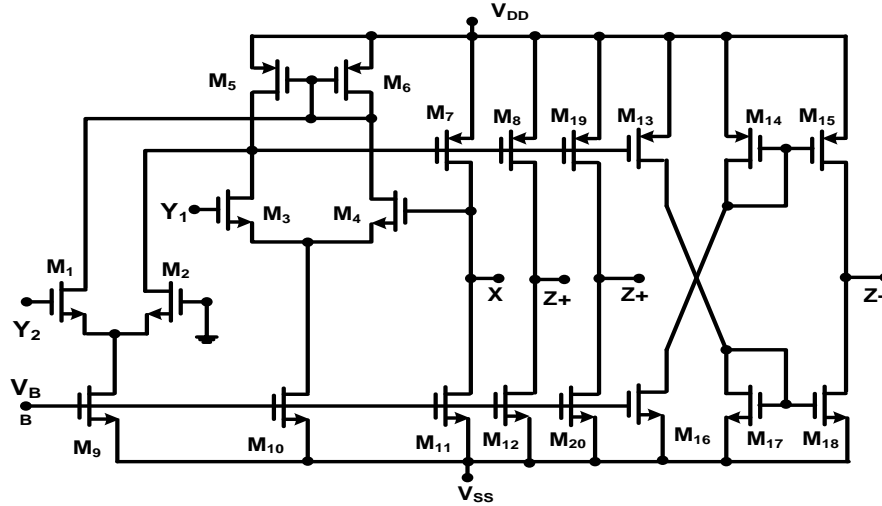


Fig 1(b): The CMOS implementation of a DVCC with two Z+ and one Z- outputs

3. THE DPR CIRCUITS

The three new differential precision rectifiers using single DVCC are given in “Figure 2” where the forced current into high gate resistances saturates the voltage at the node 5, which is enough to switch ON or switch OFF the MOSFET switches M_1 through M_4 . The circuit of “Figure 2(a)” gives half wave differential precision rectifier with two different outputs. In “Figure 2(a)” during positive cycle the NMOS switch M_1 is ON and the positive cycle current passes through resistor R_2 at node 3 while during negative cycle M_1 is OFF and hence there will be no current through R_2 . Thus the half wave rectified voltage output is available at node 3. Similarly, during positive cycle M_2 is OFF and so no current through R_3 at node 4 while during negative cycle M_2 is ON and thus the inverted negative cycle current from Z- terminal of the DVCC passes through resistor R_3 at node 4 which results in the half wave rectification at node 4. Thus at node 3 only positive half wave rectified voltage output is available while at node 4 inverted negative half wave rectified output voltage is present.

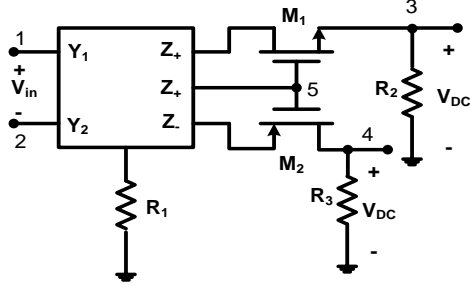


Fig 2(a): The HW differential precision rectifier circuit

The routine analysis yields its magnitude of output DC voltage at node 3 as well as at node 4 as follows.

$$V_{DC} = \left(\frac{V_{mi}}{\pi} \right) \frac{R_2}{R_1} \quad (3)$$

Where V_{mi} is the peak of the input AC voltage.

In “Figure 2(b)” also during positive cycle the NMOS switch M_1 is ON and PMOS switch M_2 is OFF and thus the positive cycle current passes through resistor R_2 at node 3. While during negative cycle M_1 is OFF and M_2 is ON and thus the inverted negative cycle current also passes through resistor R_2 in same direction and results the full wave rectification. Thus the circuit of “Figure 2(b)” gives full wave differential precision rectifier with single ended output and its output DC voltage at node 3 can be expressed as

$$V_{DC} = \left(\frac{2V_{mi}}{\pi} \right) \frac{R_2}{R_1} \quad (4)$$

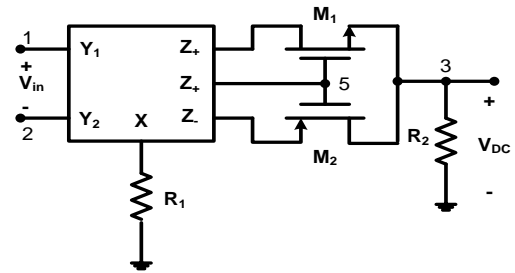


Fig 2(b): The FW differential precision rectifier circuit with single output-DPRSO

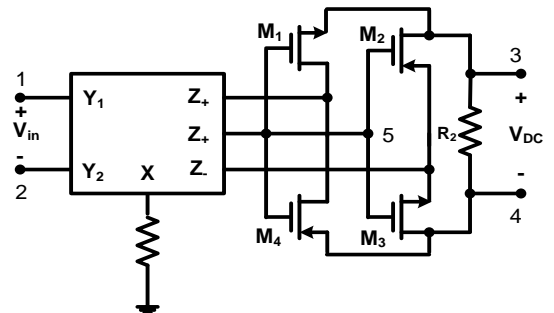


Fig 2(c): The FW differential precision rectifier circuit with differential output-DPRDO

In “Figure 2(c)” during the positive cycle the NMOS switches M_1 and M_3 are ON while PMOS switches M_2 and M_4 are OFF and thus the positive cycle current passes through resistor R_2 . During negative cycle the NMOS switches M_1 and M_3 are OFF while PMOS switches M_2 and M_4 are ON and thus the inverted negative cycle current also passes through resistor R_2 in same direction and results the full wave rectification. Thus the circuit of “Figure 2(c)” gives full wave differential precision rectifier with differential output and its output DC voltage is same as given in equation (4). It is to be noted that the ON resistance of the CMOS switches is low at signal magnitude [20]. In precision rectifiers as the signal magnitude is significantly small, the switch resistances may play insignificant role.

Taking the tracking errors of the DVCC into account, the relationship of the terminal voltages and currents of the DVCC can be rewritten as

$$\begin{aligned} I_{Y1} &= I_{Y2} = 0 \\ V_X &= \beta(V_{Y1} - V_{Y2}) \\ I_{Z+} &= +\alpha I_X \\ I_{Z-} &= -\alpha I_X \end{aligned} \quad (5)$$

where, β is the voltage transfer gain from Y to X terminal and α is the current transfer gain of the DVCC from X to Z terminal. The above transfer gains slightly deviate from unity and the deviations are quite small and technology dependent [14]. By including these non-ideal effects the DVCC the DC output of the HW-DPR given in equation (3) is modified as

$$V_{DC} = \alpha\beta\left(\frac{V_{mi}}{\pi}\right)\frac{R_2}{R_1} \quad (6)$$

Similarly, the DC output of the full wave DPRSO as well as for DPRDO given in equation (4) is changed to

$$V_{DC} = \alpha\beta\left(\frac{2V_{mi}}{\pi}\right)\frac{R_2}{R_1} \quad (7)$$

Thus, from equation (6) and (7) it is observed that the magnitude of the DC outputs of the DPR may get slightly affected due to non idealities of the DVCC. However, this reduction in gain may easily be adjusted through two resistors ratio.

4. DESIGN AND VERIFICATION

The realized differential precision rectifiers of “Figure 2” were designed and verified by performing PSPICE simulation with supply voltage ± 1.5 V, using CMOS TSMC 0.25 μm technology parameters. The aspect ratios used are given in the Table 1. All the DPR were designed for unity gain with $R_1 = R_2 = R_3 = 100 \Omega$. The observed wave shapes of the designed

HW-DPR of “Figure 2(a)” and FW-DDPSO of “Figure 2(b)” are respectively, shown in “Figure 3” and “Figure 4”. The

Table 1: The aspect ratios of the MOSFETs of the DPCCII

MOSFETs	W μm	L μm
M_1, M_2, M_3, M_4	1.6	1
M_5, M_6	8	1
$M_7, M_8, M_{13}, M_{14}, M_{15}, M_{19}$	20	1
M_9, M_{10}	29	1
$M_{11}, M_{12}, M_{16}, M_{17}, M_{18}, M_{20}$	90	1

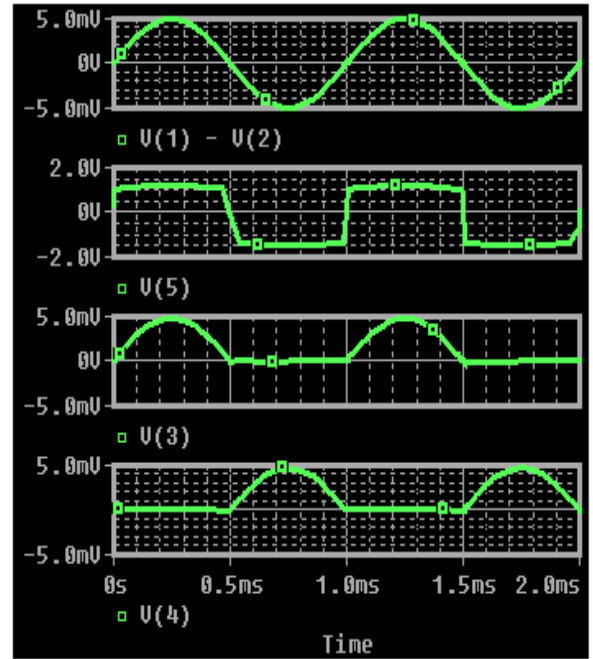


Fig 3: The differential input and differential output of the HW-DPRSO at 1 KHz

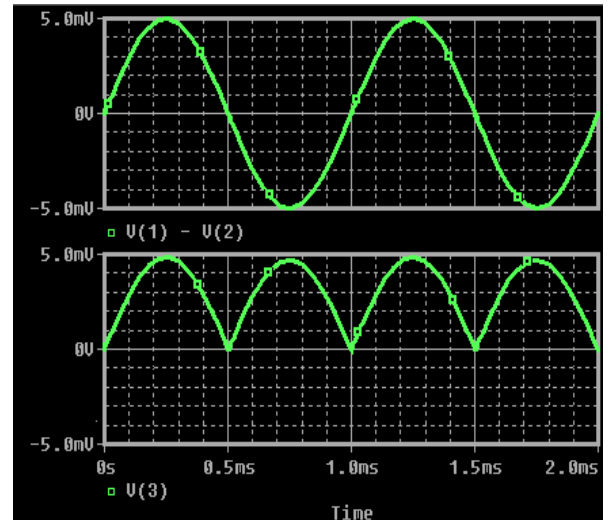


Fig 4: The differential input and differential output of the DPRSO at 1 KHz

observed wave shapes of the designed FW-DPRDO of “Figure 2(c)” are given in “Figure 5” at 1 KHz, 100 KHz and 1 MHz . To demonstrate the gain capability, the DPRDO of “Figure 2(c)” was designed for a gain of 100 by selecting $R_1 = 0.3 \text{ K}\Omega$ and $R_2 = 30 \text{ K}\Omega$. The observed wave shapes at 10 KHz are shown in “Figure 5(d)”. The observed DC transfer characteristics of the DPRDO is given in “Figure 6” which shows a high degree of linearity and equal swing for both positive and negative variations of signal amplitude. Thus the observed results of “Figure 3” through “Figure 6”, show the close conformity with the theory.

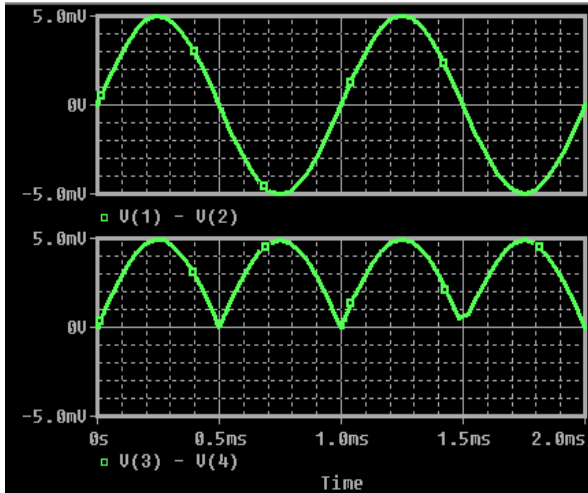


Fig 5(a): The differential input and differential output of the DPRDO at 1 KHz

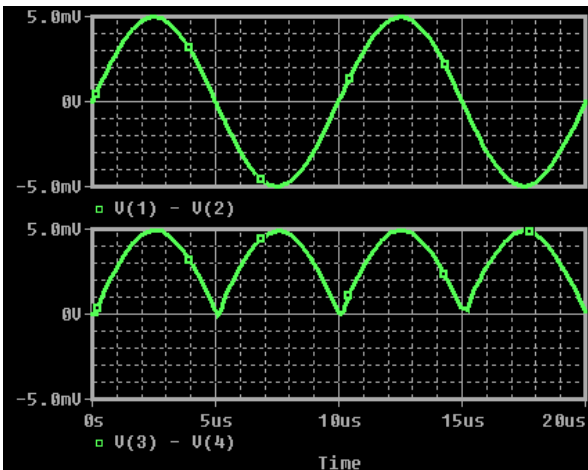


Fig 5(b): The differential input and differential output of the DPRDO at 100 KHz

5. COMPARATIVE STUDY

An exhaustive comparison of various precision rectifiers is given in reference [32]. Here the novel precision rectifiers presented in this paper are compared with the precision rectifiers of reference [32] and the comparative results are given in the Table 2. The comparative results show that the proposed differential precision rectifiers use lesser number of active and passive components and provide the differential input in all the three cases, while the proposed circuit of “Figure 2(c)” provides the differential input as well as differential output.

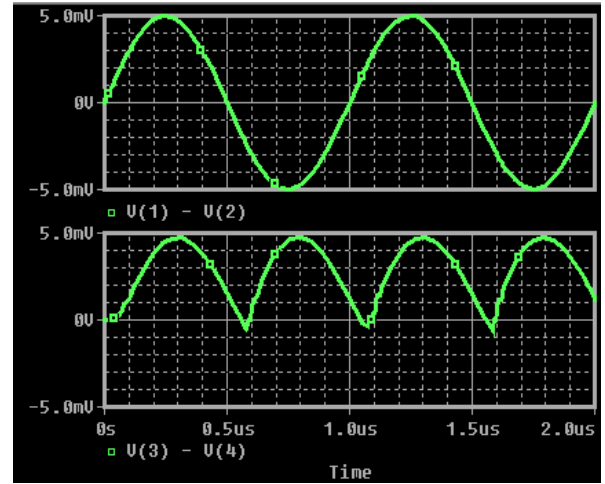


Fig 5(c): The differential input and differential output of the DPRDO at 1 MHz

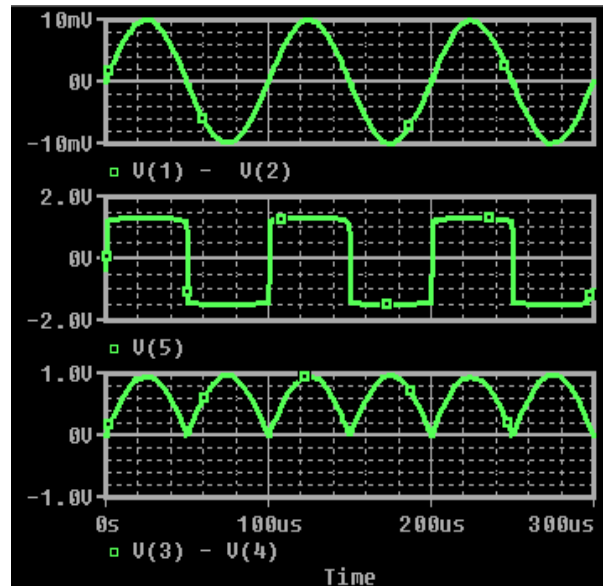


Fig 5(d): The differential input and differential output of the DPRDO at 10 KHz and gain of 100.

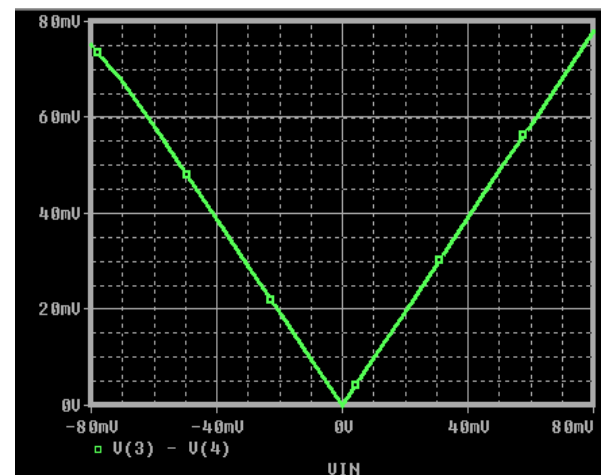


Fig 6: The dc transfer characteristics of the DPRDO

Table 2: Comparative results

Reference No.	No. of Devices	No. of Resistors	HW/FW	Operating Frequency	Gain Facility	Type of Input/Output
Reference[32] (Fig.4)	2 CCII, 1 MOSFET	4	Yes/Yes	1MHz	No	Single Ended/Single Ended
Reference[32] (Fig.6)	2 DVCC, 1 MOSFET	3	Yes/Yes	1MHZ	No	Single Ended/Single Ended
Proposed Fig. 2(a)	1 DVCC, 2 MOSFET	2	Yes/No	1MHz	Yes	Differential/Single Ended
Proposed Fig. 2(b)	1 DVCC, 2 MOSFET	2	No/Yes	1MHZ	Yes	Differential/Single Ended
Proposed Fig. 2(c)	1 DVCC, 4 MOSFET	2	No/Yes	1MHz	Yes	Differential/Differential

6. CONCLUSION

Three novel differential precision rectifier circuits are presented using single CMOS differential voltage current conveyor. One of the realized differential precision rectifiers provides half wave voltage output. The other two circuits give full wave voltage outputs. Among the two full wave circuits, the first one provides differential precision rectifier with single ended output, while the other full wave differential precision rectifier gives differential output. All the realized differential precision rectifiers use low component counts and possess the gain control facility through two resistors ratio. The effects of non ideal gains of the differential voltage current conveyor on the differential precision rectifiers are also studied. The realized differential precision rectifier circuits are designed and verified using PSPICE and the results thus obtained justify the theory.

7. REFERENCES

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